UNISONIC TECHNOLOGIES CO., LTD

UTG60N120-G2

Preliminary

Insulated Gate Bipolar Transistor

1200V TRENCH GATE FIELD-STOP IGBT

DESCRIPTION

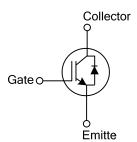
The UTC **UTG60N120-G2** is an Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

The UTC **UTG60N120-G2** is suitable for the resonant or soft switching applications.

■ FEATURES

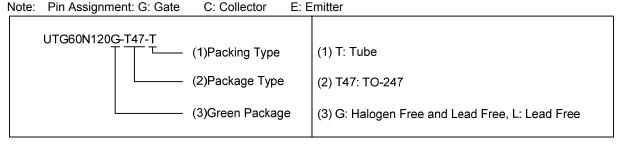
- * High switching speed
- * High avalanche ruggedness
- * Low saturation voltage: $V_{CE(sat), typ} = 1.57V @ I_C = 60A (T_C = 25^{\circ}C)$
- * Low switching loss: $E_{OFF, typ}$ =4.43mJ @ I_{C} =60A (T_{C} =25°C)



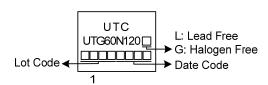


ORDERING INFORMATION

Ordering Number		Daalraga	Pin Assignment			Doolsing
Lead Free	Halogen Free	Package	1	2	3	Packing
UTG60N120L-T47-T	UTG60N120G-T47-T	TO-247	G	С	E	Tube



■ MARKING



1 TO-247

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ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-Emitter Voltage		V _{CES}	1200	V	
Gate-Emitter Voltage		V_{GES}	±20	V	
Cantinuous Callacter Current	T _C =25°C	Ic	120	Α	
Continuous Collector Current	T _C =100°C		60	Α	
Collector Current Pulsed (Note 1)		I _{CM}	240	Α	
Diada Farward Current	T _C =25°C		120	Α	
Diode Forward Current	T _C =100°C	l _F	60	Α	
Short Circuit Withstand Time $V_{GE} = 15V, V_{CC} \le 200V$					
Allowed number of short circuits < 10	000	t _{SC}	5	μs	
Time between short circuits: ≥1.0s					
T _{VJ} = 25°C					
Power Dissipation	T _C =25°C	P_D	285	W	
Operating Junction Temperature		TJ	-40 ~ +175	°C	
Storage Temperature Range		T _{STG}	-55 ~ +175	°C	

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

THERMAL DATA

PARAMETER	SYMBOL	RATING	UNIT
Junction to Case	θ_{JC}	0.44	°C/W

ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise noted)

	1	1	MIN	1		1		
PARAMETER	SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT		
Off Characteristics								
Collector-Emitter Breakdown Voltage	BV _{CES}		1200			V		
Collector Cut-Off Current	I _{CES}	V _{CE} =V _{CES} , V _{GE} =0V			5	μΑ		
G-E Leakage Current	I _{GES}	V _{GE} =V _{GES} , V _{CE} = 0V			±100	nA		
On Characteristics								
Gate to Emitter Threshold Voltage	$V_{GE(TH)}$	I _C =250μA, V _{CE} =V _{GE}	4.5		7.5	V		
Calle star to Ensitter Caturation Valtage	V _{CE(SAT)}	I _C =60A, V _{GE} =15V		1.57	2.0	V		
Collector to Emitter Saturation Voltage		I _C =60A, V _{GE} =15V, T _C =125°C		1.9		V		
Dynamic Characteristics								
Input Capacitance	C _{IES}			6680		pF		
Output Capacitance	C _{OES}	V _{CE} =25V, V _{GE} =0V, f=1MHz		139		рF		
Reverse Transfer Capacitance	C _{RES}			70		pF		
Switching Characteristics								
Total Gate Charge	Q_{G}			282		nC		
Gate-Emitter Charge	Q_GE	V _{CE} =600V, I _C =60A, V _{GE} =15V		52		nC		
Gate-Collector Charge	Q_{GC}			165		nC		
Turn-On Delay Time	t _{DON)}			44		ns		
Rise Time	t _R			31		ns		
Turn-Off Delay Time	t _{DOFF)}	Vcc=600V, Ic=60A, Rg=5Ω,		275		ns		
Fall Time	t _F	V _{GE} =0~15V, L=500uH		179		ns		
Turn-On Switching Loss	E _{ON}			3.69		mJ		
Turn-Off Switching Loss	E _{OFF}			4.43		mJ		
SOURCE- DRAIN DIODE RATINGS AN		RISTICS						
Forward Voltage Drop	V_{FM}	I _F =60A			2.5	V		
Reverse Recovery Time	t _{rr}	I _F =60A,		50.7		ns		
Reverse Recovery Charge	Q _{rr}	dl/dt=100A/ <i>µ</i> S		2.66		μC		
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^{2.} Pulse width limited by maximum junction temperature.

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